



MCH3382

P-Channel Power MOSFET -12V, -2A, 198mΩ, Single MCPH3

ON Semiconductor®

<http://onsemi.com>

Features

- ON-resistance $R_{DS(on)1}=152m\Omega$ (typ.)
- 1.2V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-12	V
Gate-to-Source Voltage	V_{GSS}		± 9	V
Drain Current (DC)	I_D		-2	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-8	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.8	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

This product is designed to "ESD immunity < 200V**", so please take care when handling.

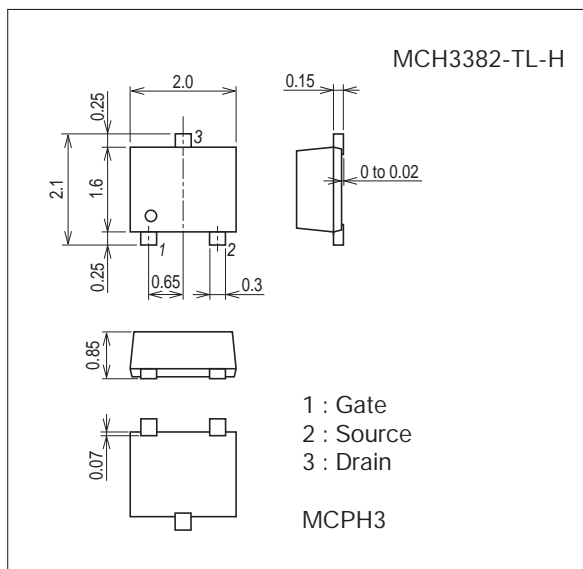
* Machine Model

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

7019A-003

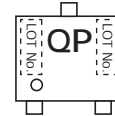
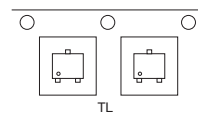


Product & Package Information

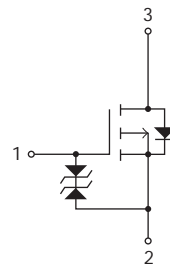
- Package : MCPH3
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

Packing Type : TL

Marking



Electrical Connection

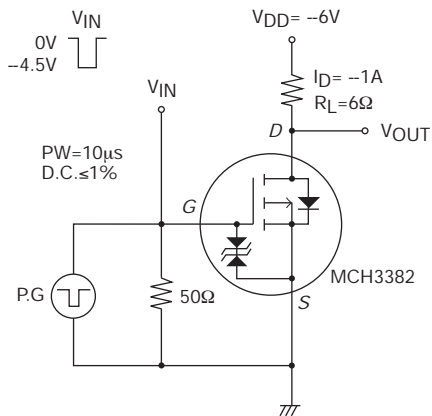


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Electrical Characteristics at Ta=25°C

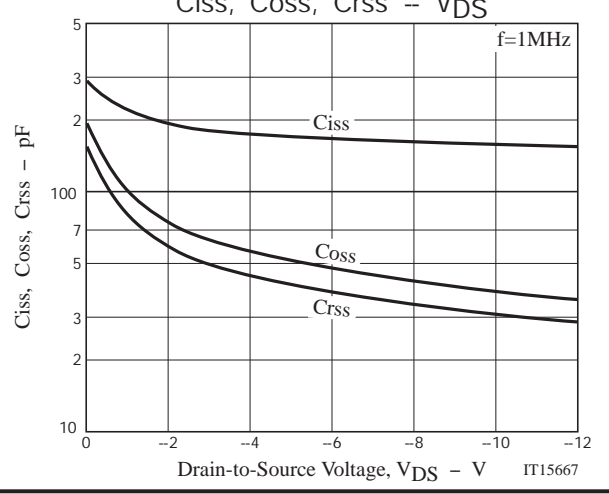
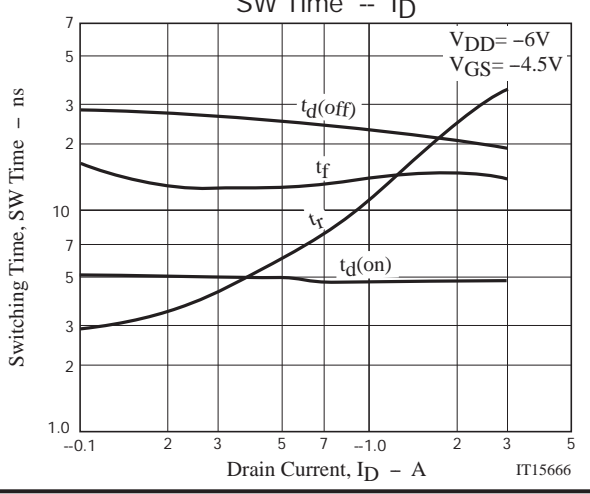
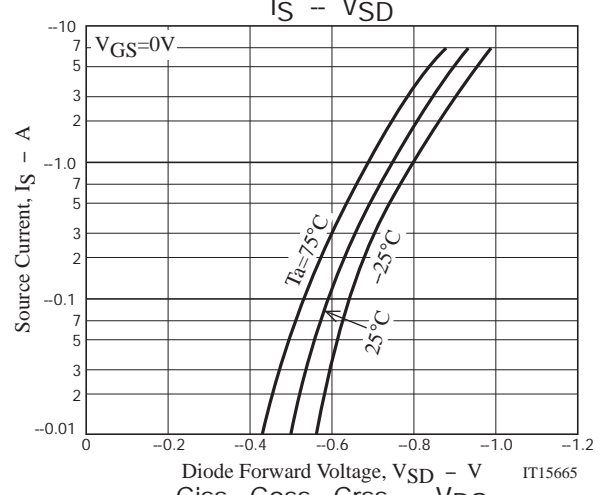
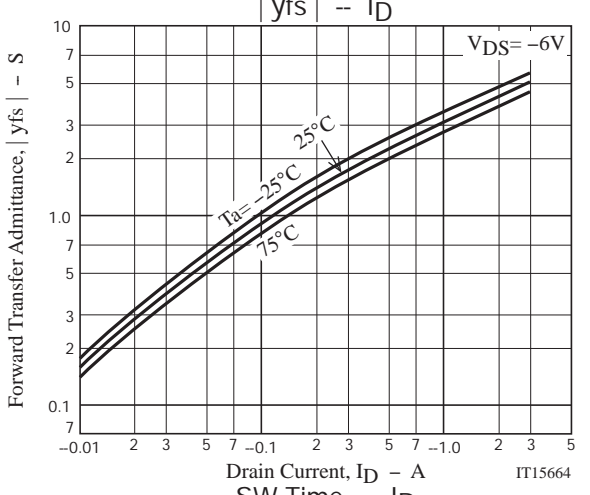
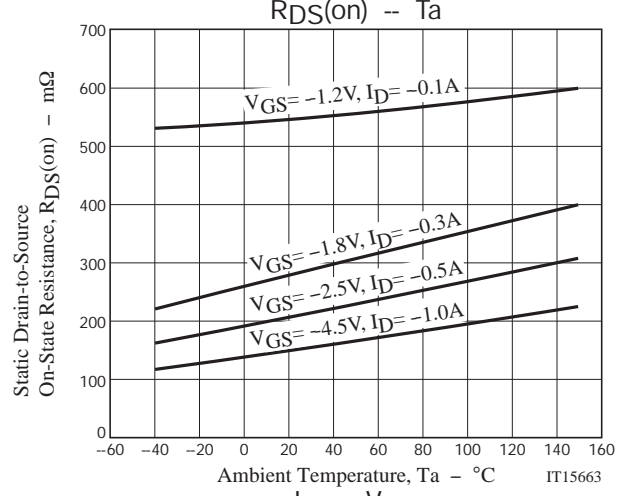
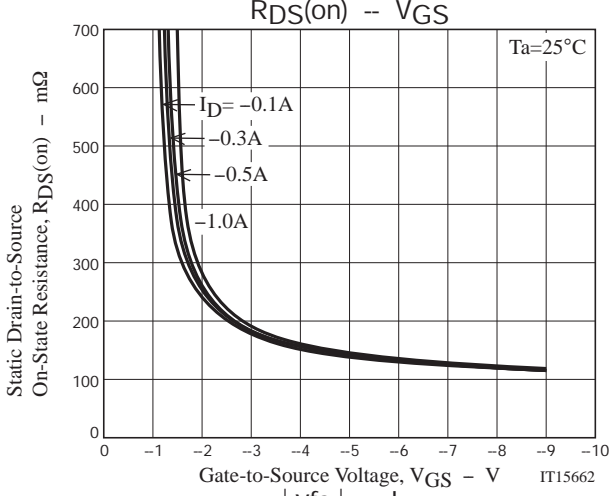
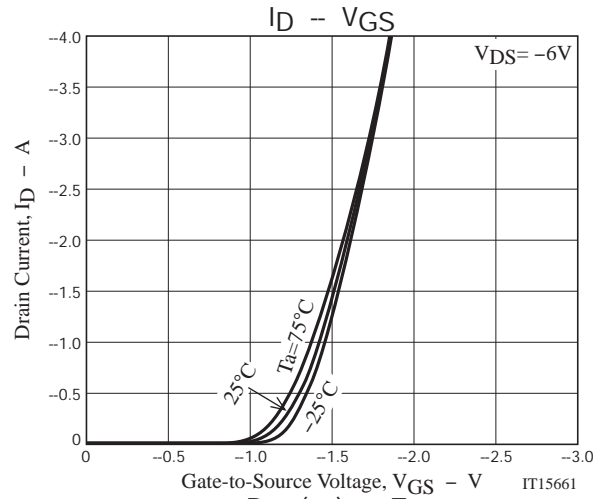
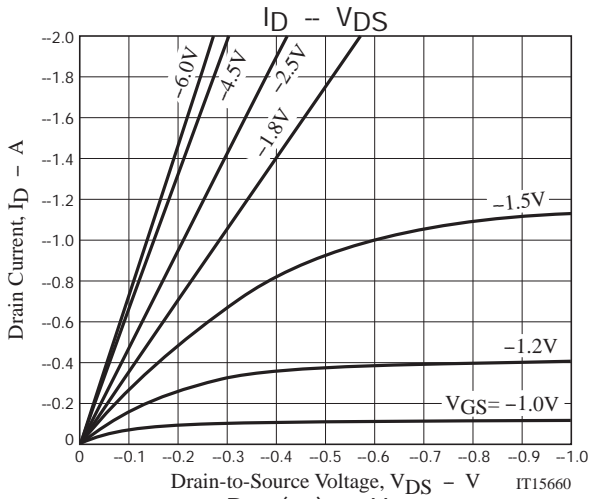
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-12			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-12V, VGS=0V			-10	μA
Gate-to-Source Leakage Current	IGSS	VGS=±7.2V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-6V, ID=-1mA	-0.3		-0.9	V
Forward Transfer Admittance	yfs	VDS=-6V, ID=-1A		3		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-1A, VGS=-4.5V		152	198	mΩ
	RDS(on)2	ID=-0.5A, VGS=-2.5V		212	297	mΩ
	RDS(on)3	ID=-0.3A, VGS=-1.8V		286	429	mΩ
	RDS(on)4	ID=-0.1A, VGS=-1.2V		520	1040	mΩ
Input Capacitance	Ciss	VDS=-6V, f=1MHz		170		pF
Output Capacitance	Coss			50		pF
Reverse Transfer Capacitance	Crss			40		pF
Turn-ON Delay Time	t _{d(on)}		See specified Test Circuit.		4.8	
Rise Time	t _r			11		ns
Turn-OFF Delay Time	t _{d(off)}			23		ns
Fall Time	t _f			14		ns
Total Gate Charge	Qg	VDS=-6V, VGS=-4.5V, ID=-2A			2.3	
Gate-to-Source Charge	Qgs			0.40		nC
Gate-to-Drain "Miller" Charge	Qgd			0.46		nC
Diode Forward Voltage	VSD		IS=-2A, VGS=0V		-0.85	-1.2

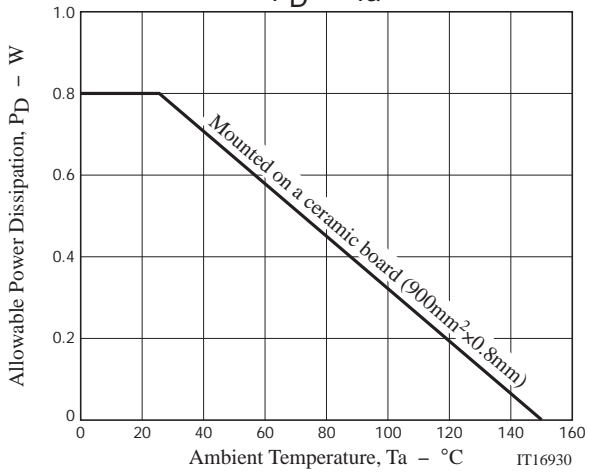
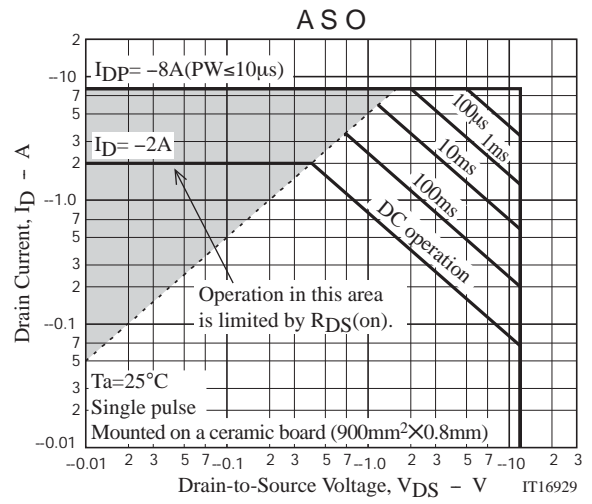
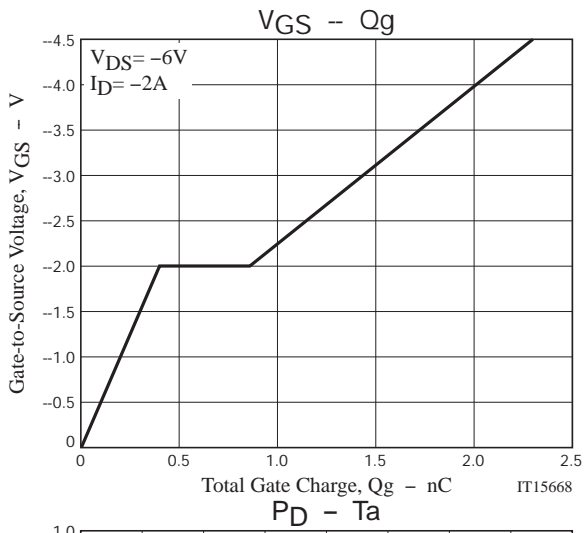
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
MCH3382-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free





Taping Specification

MCH3382-TL-H

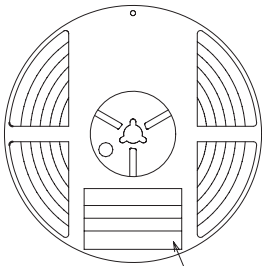
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCPH3	MCPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

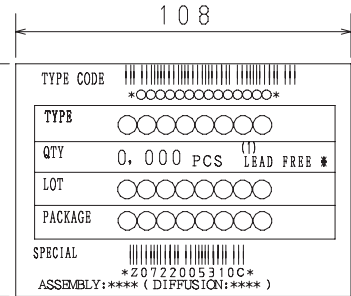
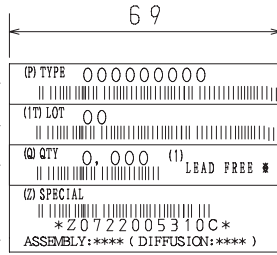
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Type No.
LOT No.
Quantity
Origin

Reel label



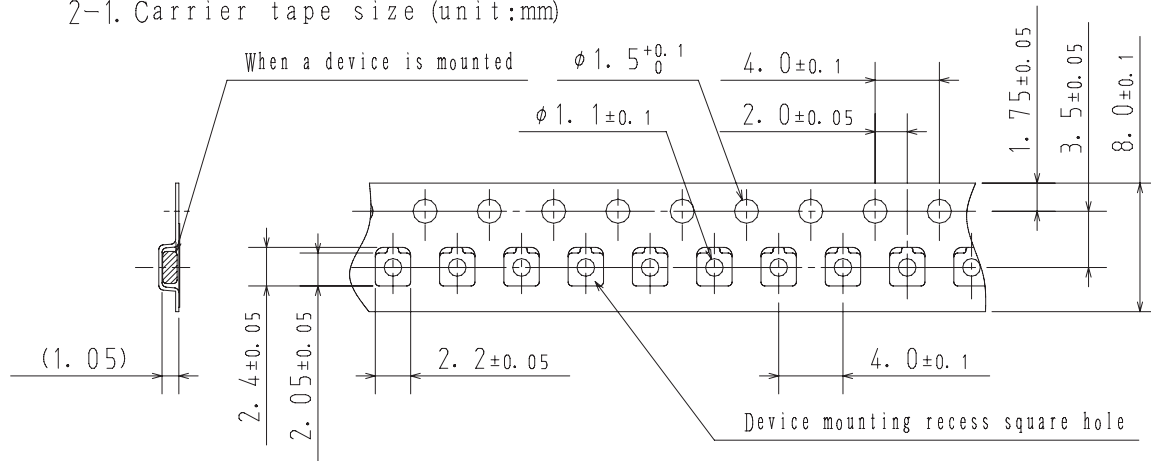
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

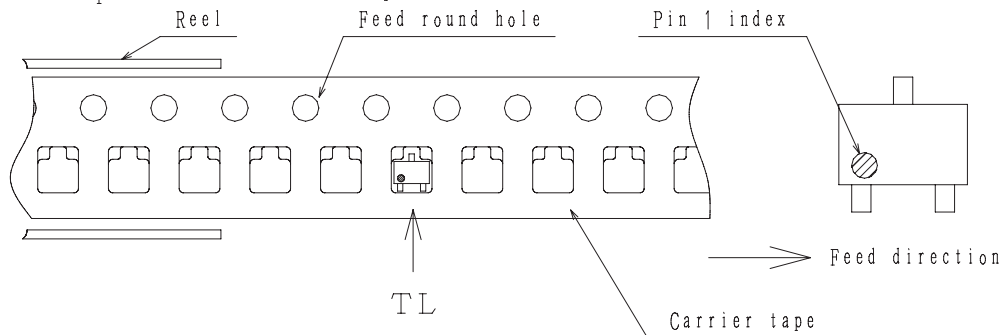
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



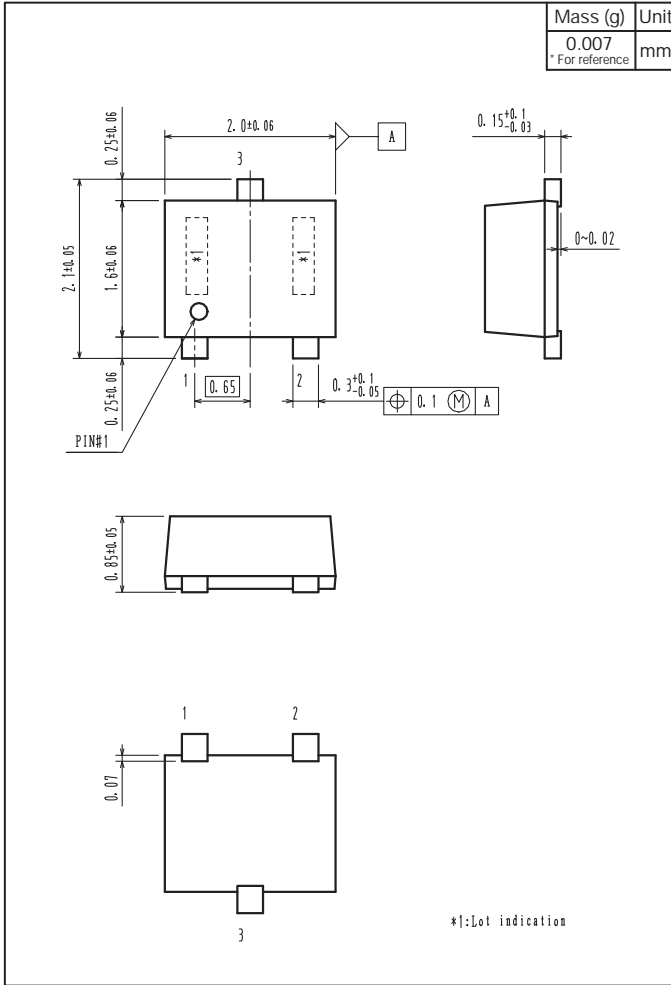
2-2. Device placement direction



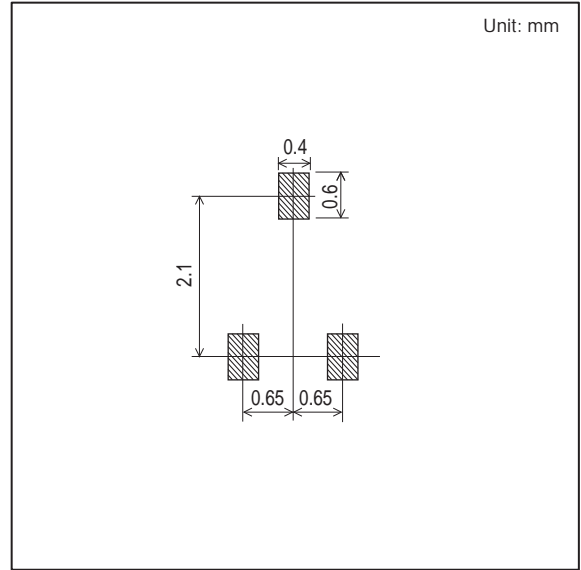
Those with pin 1 index on the feed hole side.....TL

MCH3382

Outline Drawing MCH3382-TL-H



Land Pattern Example



Note on usage : Since the MCH3382 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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